

UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
09/988,272	11/19/2001	Hirotoshi Kubo	981206A	8401		
38834 7	8834 7590 07/26/2004			EXAMINER		
WESTERMAN, HATTORI, DANIELS & ADRIAN, LLP 1250 CONNECTICUT AVENUE, NW SUITE 700			HOGANS, DAVID L			
			ART UNIT	PAPER NUMBER		
WASHINGTO	N, DC 20036		2813			
			DATE MAILED: 07/26/2004			

Please find below and/or attached an Office communication concerning this application or proceeding.

				ab		
		Application No.	Applicant(s)	. •		
Office Action Summary		09/988,272	KUBO ET AL.			
		Examiner	Art Unit			
		David L. Hogans	2813			
Period fo	The MAILING DATE of this communication ap or Reply	pears on the cover sheet with the	correspondence address			
A SH THE - Exte after - If the - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPLEMAILING DATE OF THIS COMMUNICATION. Insions of time may be available under the provisions of 37 CFR 1. SIX (6) MONTHS from the mailing date of this communication. In period for reply specified above is less than thirty (30) days, a replement of the reply is specified above, the maximum statutory period preserved by the office later than three months after the mailing department of the reply will, by statusting the reply will be office later than three months after the mailing department term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be to bly within the statutory minimum of thirty (30) da will apply and will expire SIX (6) MONTHS from the, cause the application to become ABANDON	imely filed sys will be considered timely. In the mailing date of this communication. ED (35 U.S.C. § 133).			
Status						
1)[🖂	Responsive to communication(s) filed on 271	Mav 2004.	•			
,	•	is action is non-final.				
• —	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.					
Disposit	ion of Claims					
5)□ 6)⊠ 7)□	Claim(s) 12-15 and 22-24 is/are pending in the 4a) Of the above claim(s) 16-21 is/are withdrated claim(s) is/are allowed. Claim(s) 12-15 and 22-24 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/	wn from consideration.		. •		
Applicat	ion Papers					
10)⊠	The specification is objected to by the Examin The drawing(s) filed on <u>07 November 2003</u> is/Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Examin Theoretical Section 1.	fare: a) \boxtimes accepted or b) \square objected drawing(s) be held in abeyance. So action is required if the drawing(s) is o	ee 37 CFR 1.85(a). bjected to. See 37 CFR 1.121(d).			
Priority	under 35 U.S.C. § 119					
a)	Acknowledgment is made of a claim for foreig All b) Some * c) None of: 1. Certified copies of the priority documer 2. Certified copies of the priority documer 3. Copies of the certified copies of the priority documer application from the International Burea See the attached detailed Office action for a list	nts have been received. Its have been received in Applica Ority documents have been received Au (PCT Rule 17.2(a)).	tion No /ed in this National Stage			
Attachmer	nt(s)					
	ce of References Cited (PTO-892)	4) Interview Summar				
3) Infor	ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08 er No(s)/Mail Date	Paper No(s)/Mail I 5) Notice of Informal 6) Other:	Patent Application (PTO-152)			

DETAILED ACTION

This Office Action is in response to the Amendment filed on May 27, 2004.

Status of Claims

Claims 12-15 and 22-24 are pending. Claims 16-21 are withdrawn. Claims 1-11 are cancelled. Claim 24 is new.

EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Stephen G. Adrian on June 18, 2004.

The application has been amended as follows: Claim 12 line 17; delete "material" and insert "layer".

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Application/Control Number: 09/988,272 Page 3

Art Unit: 2813

2. Claims 12-14 and 22-24 are rejected under 35 U.S.C. 102(e) as being anticipated by 5,631,484 to Tsoi et al.

In reference to Claims 12, Tsoi et al. teaches:

- forming a drain layer (28) of a first conduction type (n) on a surface of a semiconductor substrate (27) of the first conduction type (n); (See Figures 2-14 and columns 2-8 lines 30-22)
- forming a first insulating film (33) on said drain layer (28); (See Figures 2-14 and columns 2-8 lines 30-22)
- forming a first conductive layer (34) on said first insulating film (33); (See Figures
 2-14 and columns 2-8 lines 30-22)
- forming a second insulating film (37) on said first conductive layer (34); (See
 Figures 2-14 and columns 2-8 lines 30-22)
- patterning said second insulating film, said first conductive layer, and said first insulating film, to form a gate insulating film (33) from said first insulating film, and a gate electrode (34) from said first conductive layer; (See Figures 2-14 and columns 2-8 lines 30-22)
- implanting an impurity of a second conduction type (p) opposite to the first conduction type into a surface of said drain layer using said gate electrode as a mask, thereby forming a channel region of the second conduction type (47); (See Figures 2-14 and columns 2-8 lines 30-22)

Application/Control Number: 09/988,272

Art Unit: 2813

• implanting an impurity of the first conduction type (n) into said channel region with using said gate electrode as a mask, thereby forming an impurity region of the first conduction type (52); (See Figures 2-14 and columns 2-8 lines 30-22)

Page 4

- forming a third insulating film (56) so as to cover a surface of the impurity region, side walls of said gate insulating film, said gate electrode, and said second insulating film, and an upper face of said second insulating film; (See Figures 2-14 and columns 2-8 lines 30-22)
- etching back said third insulating film to form a side wall insulator (58) of said
 third insulating film, by maintaining said third insulating film selectively on side
 walls of said gate insulating film, said gate electrode, and said second insulating
 film; (See Figures 2-14 and columns 2-8 lines 30-22)
- etching the impurity region (52) to form a recess (66) so as to penetrate the impurity region, thereby forming a source region (152) of the impurity region;
 (See Figures 2-14 and columns 2-8 lines 30-22) and
- forming a second conductive layer (71) on an entire surface, and patterning said second conductive layer, thereby forming a wiring layer (See Figures 2-14 and columns 2-8 lines 30-22)

In reference to Claim 13, Tsoi et al. teaches:

introducing an impurity of the second conduction type (p) into the bottom of the
 recess to form a body contact region (121) of the second conduction after etching

Application/Control Number: 09/988,272 Page 5

Art Unit: 2813

the impurity region prior to forming a second conductive layer (71) (See Figures 2-14 and columns 2-8 lines 30-22)

In reference to Claim 14, Tsoi et al. teaches:

- forming a mask pattern (61) having an opening located in a center of the impurity region and covering an entire surface except for the opening before etching the impurity region; (See Figures 2-14 and columns 2-8 lines 30-22)
- etching the impurity region by using the mask pattern to form a recess (66)
 deeper than the impurity region (52), thereby forming a source region (152) of the
 impurity region remained; (See Figures 2-14 and columns 2-8 lines 30-22) and
- introducing an impurity of the second conduction type (p) into the bottom of the recess to form a body contact region (121) of the second conduction type (See Figures 2-14 and columns 2-8 lines 30-22)

In reference to Claim 22, Tsoi et al. teaches:

an upper surface and a side surface of the source region are directly contacted
 with the wiring layer (71) (See Figures 2-14 and columns 2-8 lines 30-22)

In reference to Claim 23, Tsoi et al. teaches:

 an opening of the mask pattern (61) is formed smaller than a region of the impurity region between the adjacent sidewall insulators (58) (See Figures 2-14 and columns 2-8 lines 30-22) In reference to Claim 24, Tsoi et al. teaches:

 wherein said third insulating film is formed in one step (56) (See Figures 2-14 and columns 2-8 lines 30-22)

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claim 15 is rejected under 35 U.S.C. 103(a) as being unpatentable over 5,631,484 to Tsoi et al. in view of Applicant's Admitted Prior Art (AAPA).

Incorporating all arguments of Claim 12 and noting that Tsoi et al. fails to explicitly teach a fourth insulating layer formed on the substrate that is patterned so as to remain a peripheral region on the substrate.

However, Applicant's specification, page 2 lines 10-18, discloses a thick oxide that is patterned to be formed in bonding pad site regions (i.e. – on the periphery of the substrate).

It would have been obvious to one of ordinary skill in the art to modify Tsoi by incorporating a fourth insulating layer formed on the substrate that is patterned so as to remain a peripheral region on the substrate, as taught by Applicant's Admitted Prior Art, to create regions for bonding pads.

Response to Arguments

5. Applicant's arguments filed May 27, 2004, have been fully considered but they are not persuasive.

The crux of Applicant's argument is that Applicant's third insulating film is only comprised by one material/layer and that 5,631,484 to Tsoi et al. fails to teach this limitation. The Examiner kindly refers Applicant to column 4 lines 60-65, where Tsoi et al. teaches that layer 54 need not be present. Therefore, Tsoi et al. teaches all the limitations of Applicant's claimed invention (i.e. – the third insulating film is only comprised by one layer(56)).

Conclusion

6. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of

Art Unit: 2813

the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to David L. Hogans whose telephone number is (571) 272-1691. The examiner can normally be reached on M-F (7:30-4:30).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead Jr. can be reached on (571) 272-1702. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

DH

CARL WHIZEHEAD JUN.
SUPERVISORY PATENT EXAMINER:
TECHNOLOGY CENTER 2808